NSN 5962-01-351-4985

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View Online at https://aerobasegroup.com/nsn/5962-01-351-4985

Overall Length:
1.280 inches
Overall Height:
0.400 inches
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Monolithic and static operation and w/disable and burn in and bidirectional
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
85.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
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Capitance Rating Per Characteristic: 30.00 output picofarads Time Rating Per Chacteristic:

70.00 nanoseconds access

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Memory Device Type:
Ram
Special Features:
Nuclear hardness critical item
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: